



# PSMN5R6-60YL

N-channel 60 V, 5.6 mΩ logic level MOSFET in LPAK56

3 June 2016

Product data sheet

## 1. General description

Logic level N-channel MOSFET in an LPAK56 (Power SO8) package using TrenchMOS technology. This product is designed and qualified for use in a wide range of power supply & motor control equipment.

## 2. Features and benefits

- Advanced TrenchMOS provides low  $R_{DSon}$  and low gate charge
- Logic level gate operation
- Avalanche rated, 100% tested
- LPAK provides maximum power density in a Power SO8 package

## 3. Applications

- Synchronous rectifier in LLC topology
- Chargers & adaptors with  $V_{out} < 10\text{ V}$
- Fast charge & USB-PD applications
- Battery powered motor control
- LED lighting & TV backlight

## 4. Quick reference data

Table 1. Quick reference data

| Symbol                         | Parameter                        | Conditions  |     | Min | Typ | Max | Unit |
|--------------------------------|----------------------------------|---|-----|-----|-----|-----|------|
| $V_{DS}$                       | drain-source voltage             | $25\text{ °C} \leq T_j \leq 175\text{ °C}$  |     | -   | -   | 60  | V    |
| $I_D$                          | drain current                    | $V_{GS} = 5\text{ V}$ ; $T_{mb} = 25\text{ °C}$ ; <a href="#">Fig. 2</a>  | [1] | -   | -   | 100 | A    |
| $P_{tot}$                      | total power dissipation          | $T_{mb} = 25\text{ °C}$ ; <a href="#">Fig. 1</a>  |     | -   | -   | 167 | W    |
| <b>Static characteristics</b>  |                                  |   |     |     |     |     |      |
| $R_{DSon}$                     | drain-source on-state resistance | $V_{GS} = 5\text{ V}$ ; $I_D = 25\text{ A}$ ; $T_j = 25\text{ °C}$ ; <a href="#">Fig. 11</a>  |     | -   | 5.4 | 7.2 | mΩ   |
| <b>Dynamic characteristics</b> |                                  |   |     |     |     |     |      |
| $Q_{GD}$                       | gate-drain charge                | $I_D = 25\text{ A}$ ; $V_{DS} = 48\text{ V}$ ; $V_{GS} = 5\text{ V}$ ; $T_j = 25\text{ °C}$ ; <a href="#">Fig. 13</a> ; <a href="#">Fig. 14</a> |     | -   | 12  | -   | nC   |

[1] Continuous current is limited by package.

## 5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description                       | Simplified outline   | Graphic symbol  |
|-----|--------|-----------------------------------|--|---|
| 1   | S      | source                            |  <p><b>LPAK56; Power-SO8 (SOT669)</b></p> |  |
| 2   | S      | source                            |  |   |
| 3   | S      | source                            |  |   |
| 4   | G      | gate                              |  |   |
| mb  | D      | mounting base; connected to drain |  |   |

## 6. Ordering information

Table 3. Ordering information

| Type number  | Package              |   |         |
|--------------|----------------------|---|---------|
|              | Name                 | Description   | Version |
| PSMN5R6-60YL | LPAK56;<br>Power-SO8 | Plastic single-ended surface-mounted package (LPAK56; Power-SO8); 4 leads | SOT669  |

## 7. Marking

Table 4. Marking codes

| Type number  | Marking code |
|--------------|--------------|
| PSMN5R6-60YL | 5R6L60       |

## 8. Limiting values

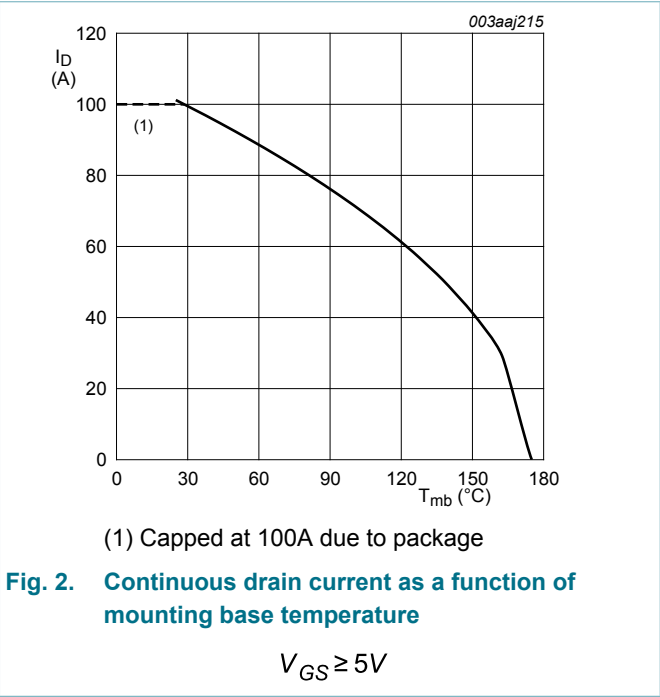
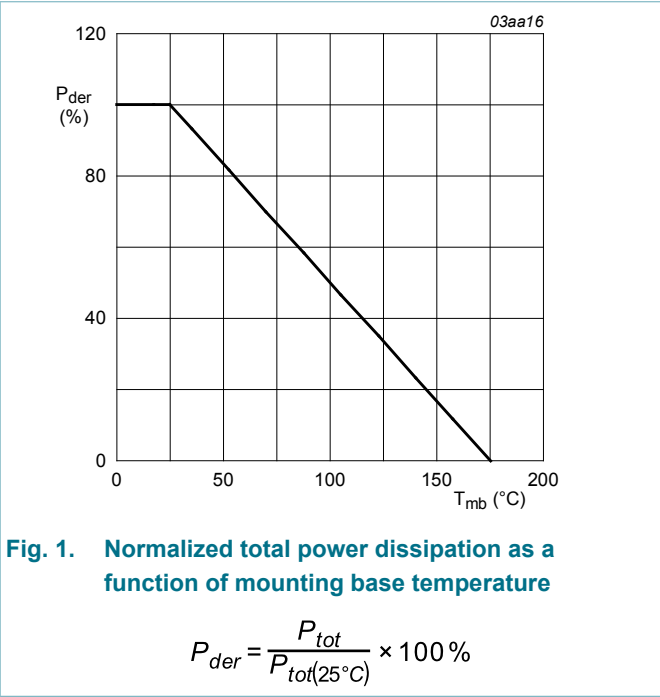
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol    | Parameter               | Conditions  |     | Min | Max | Unit |
|-----------|-------------------------|---|-----|-----|-----|------|
| $V_{DS}$  | drain-source voltage    | $25\text{ °C} \leq T_j \leq 175\text{ °C}$                                  |     | -   | 60  | V    |
| $V_{DGR}$ | drain-gate voltage      | $R_{GS} = 20\text{ k}\Omega$  |     | -   | 60  | V    |
| $V_{GS}$  | gate-source voltage     |   |     | -20 | 20  | V    |
| $P_{tot}$ | total power dissipation | $T_{mb} = 25\text{ °C}$ ; Fig. 1  |     | -   | 167 | W    |
| $I_D$     | drain current           | $V_{GS} = 5\text{ V}$ ; $T_{mb} = 25\text{ °C}$ ; Fig. 2                    | [1] | -   | 100 | A    |
|           |                         | $V_{GS} = 5\text{ V}$ ; $T_{mb} = 100\text{ °C}$ ; Fig. 2                   |     | -   | 72  | A    |
| $I_{DM}$  | peak drain current      | pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; $T_{mb} = 25\text{ °C}$ ; Fig. 3 |     | -   | 405 | A    |
| $T_{stg}$ | storage temperature     |   |     | -55 | 175 | °C   |

| Symbol               | Parameter                                    | Conditions  |        | Min | Max  | Unit |
|----------------------|--|---|--------|-----|------|------|
| T <sub>j</sub>       | junction temperature                         |   |        | -55 | 175  | °C   |
| Source-drain diode   |  |   |        |     |      |      |
| I <sub>S</sub>       | source current                               | T <sub>mb</sub> = 25 °C   | [1]    | -   | 100  | A    |
| I <sub>SM</sub>      | peak source current                          | pulsed; t <sub>p</sub> ≤ 10 μs; T <sub>mb</sub> = 25 °C   |        | -   | 405  | A    |
| Avalanche ruggedness |  |   |        |     |      |      |
| E <sub>DS(AL)S</sub> | non-repetitive drain-source avalanche energy | I <sub>D</sub> = 100 A; V <sub>sup</sub> ≤ 60 V; R <sub>GS</sub> = 50 Ω; V <sub>GS</sub> = 5 V; T <sub>j(init)</sub> = 25 °C; unclamped; Fig. 4 | [2][3] | -   | 88.2 | mJ   |

- [1] Continuous current is limited by package.
- [2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [3] Refer to application note AN10273 for further information.



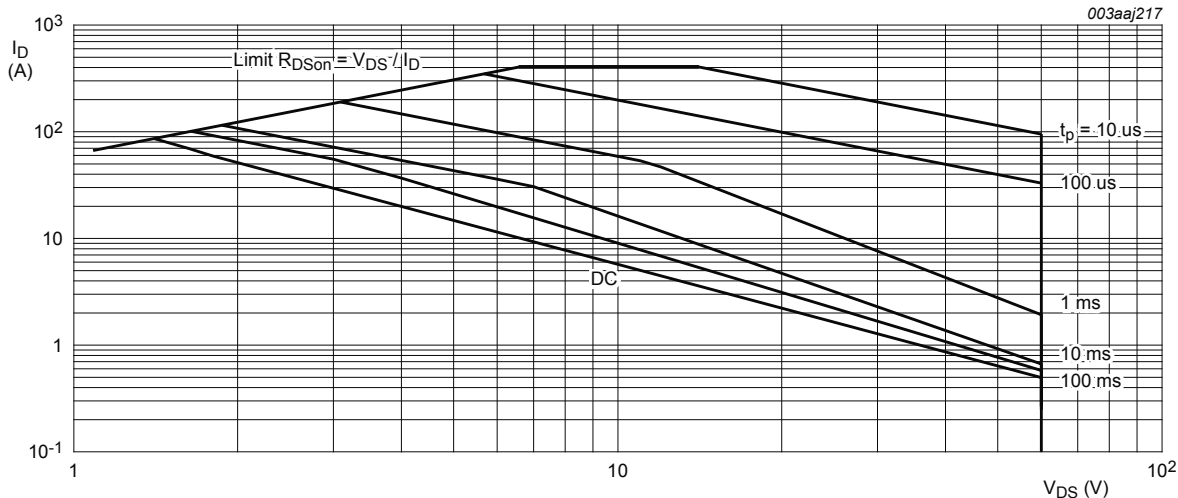


Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25^{\circ}\text{C}$ ;  $I_{DM}$  is a single pulse

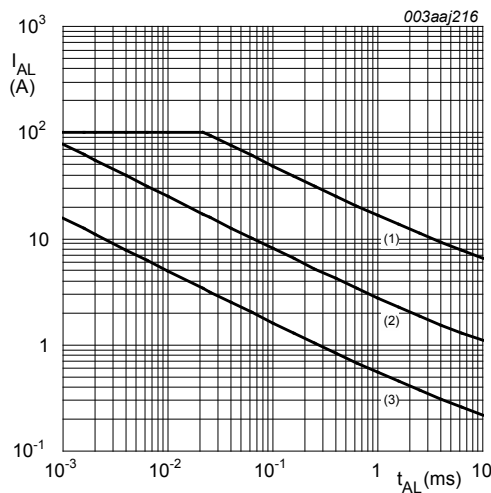


Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

(1)  $T_{j(init)} = 25^{\circ}\text{C}$ ; (2)  $T_{j(init)} = 150^{\circ}\text{C}$ ; (3) Repetitive Avalanche

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol         | Parameter   | Conditions | Min | Typ | Max | Unit |
|----------------|---|------------|-----|-----|-----|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | Fig. 5     | -   | -   | 0.9 | K/W  |

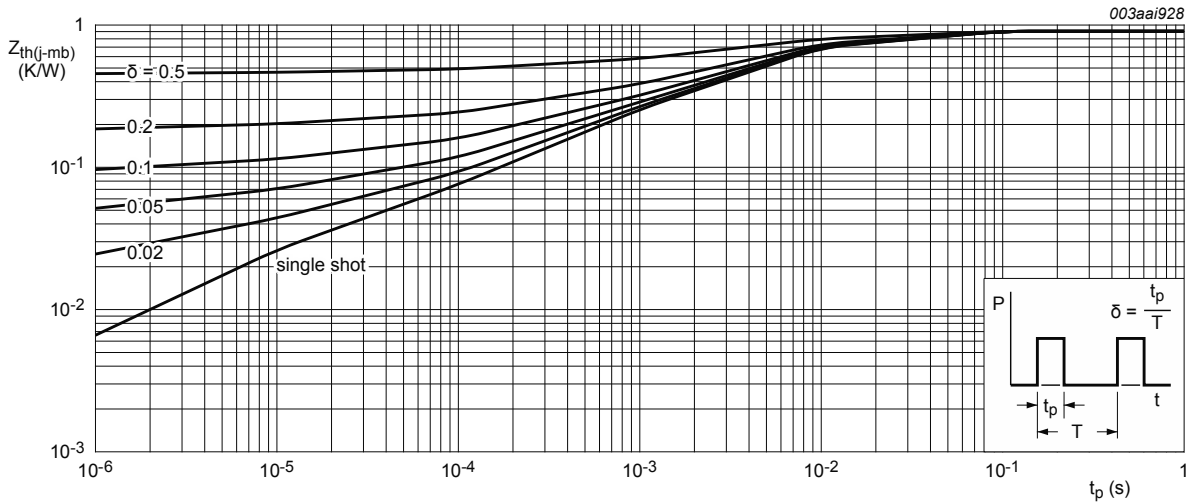


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

## 10. Characteristics

Table 7. Characteristics

| Symbol                  | Parameter                        | Conditions   |  | Min | Typ  | Max  | Unit          |
|-------------------------|----------------------------------|--|--|-----|------|------|---------------|
| Static characteristics  |                                  |  |  |     |      |      |               |
| $V_{(BR)DSS}$           | drain-source breakdown voltage   | $I_D = 250\text{ }\mu\text{A}$ ; $V_{GS} = 0\text{ V}$ ; $T_j = 25\text{ }^\circ\text{C}$  |  | 60  | -    | -    | V             |
|                         |                                  | $I_D = 250\text{ }\mu\text{A}$ ; $V_{GS} = 0\text{ V}$ ; $T_j = -55\text{ }^\circ\text{C}$   |  | 54  | -    | -    | V             |
| $V_{GS(th)}$            | gate-source threshold voltage    | $I_D = 1\text{ mA}$ ; $V_{DS}=V_{GS}$ ; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 9</a> ; <a href="#">Fig. 10</a>                                  |  | 1.4 | 1.7  | 2.1  | V             |
|                         |                                  | $I_D = 1\text{ mA}$ ; $V_{DS}=V_{GS}$ ; $T_j = -55\text{ }^\circ\text{C}$ ; <a href="#">Fig. 9</a>   |  | -   | -    | 2.45 | V             |
|                         |                                  | $I_D = 1\text{ mA}$ ; $V_{DS}=V_{GS}$ ; $T_j = 175\text{ }^\circ\text{C}$ ; <a href="#">Fig. 9</a>   |  | 0.5 | -    | -    | V             |
| $I_{DSS}$               | drain leakage current            | $V_{DS} = 60\text{ V}$ ; $V_{GS} = 0\text{ V}$ ; $T_j = 25\text{ }^\circ\text{C}$  |  | -   | 0.05 | 10   | $\mu\text{A}$ |
|                         |                                  | $V_{DS} = 60\text{ V}$ ; $V_{GS} = 0\text{ V}$ ; $T_j = 175\text{ }^\circ\text{C}$   |  | -   | -    | 500  | $\mu\text{A}$ |
| $I_{GSS}$               | gate leakage current             | $V_{GS} = 16\text{ V}$ ; $V_{DS} = 0\text{ V}$ ; $T_j = 25\text{ }^\circ\text{C}$  |  | -   | 2    | 100  | nA            |
|                         |                                  | $V_{GS} = -16\text{ V}$ ; $V_{DS} = 0\text{ V}$ ; $T_j = 25\text{ }^\circ\text{C}$   |  | -   | 2    | 100  | nA            |
| $R_{DSon}$              | drain-source on-state resistance | $V_{GS} = 5\text{ V}$ ; $I_D = 25\text{ A}$ ; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 11</a>   |  | -   | 5.4  | 7.2  | m $\Omega$    |
|                         |                                  | $V_{GS} = 10\text{ V}$ ; $I_D = 25\text{ A}$ ; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 11</a>  |  | -   | 4.7  | 5.6  | m $\Omega$    |
|                         |                                  | $V_{GS} = 5\text{ V}$ ; $I_D = 25\text{ A}$ ; $T_j = 175\text{ }^\circ\text{C}$ ; <a href="#">Fig. 11</a> ; <a href="#">Fig. 12</a>                          |  | -   | -    | 16.3 | m $\Omega$    |
| Dynamic characteristics |                                  |  |  |     |      |      |               |
| $Q_{G(tot)}$            | total gate charge                | $I_D = 25\text{ A}$ ; $V_{DS} = 48\text{ V}$ ; $V_{GS} = 10\text{ V}$ ; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 13</a> ; <a href="#">Fig. 14</a> |  | -   | 66.8 | -    | nC            |
|                         |                                  | $I_D = 25\text{ A}$ ; $V_{DS} = 48\text{ V}$ ; $V_{GS} = 5\text{ V}$ ; $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 13</a> ; <a href="#">Fig. 14</a>  |  | -   | 35   | -    | nC            |
| $Q_{GS}$                | gate-source charge               | $T_j = 25\text{ }^\circ\text{C}$ ; <a href="#">Fig. 13</a> ; <a href="#">Fig. 14</a>   |  | -   | 9.5  | -    | nC            |

| Symbol              | Parameter                    | Conditions   |  | Min | Typ  | Max  | Unit |
|---------------------|------------------------------|--|--|-----|------|------|------|
| Q <sub>GD</sub>     | gate-drain charge            |  |  | -   | 12   | -    | nC   |
| C <sub>iss</sub>    | input capacitance            | V <sub>DS</sub> = 25 V; V <sub>GS</sub> = 0 V; f = 1 MHz;<br>T <sub>j</sub> = 25 °C; <a href="#">Fig. 15</a>                     |  | -   | 3769 | 5026 | pF   |
| C <sub>oss</sub>    | output capacitance           |  |  | -   | 341  | 409  | pF   |
| C <sub>rss</sub>    | reverse transfer capacitance |  |  | -   | 185  | 253  | pF   |
| t <sub>d(on)</sub>  | turn-on delay time           | V <sub>DS</sub> = 45 V; R <sub>L</sub> = 1.8 Ω; V <sub>GS</sub> = 5 V;<br>R <sub>G(ext)</sub> = 5 Ω; T <sub>j</sub> = 25 °C      |  | -   | 19.3 | -    | ns   |
| t <sub>r</sub>      | rise time                    |  |  | -   | 36.4 | -    | ns   |
| t <sub>d(off)</sub> | turn-off delay time          |  |  | -   | 49.4 | -    | ns   |
| t <sub>f</sub>      | fall time                    |  |  | -   | 32.1 | -    | ns   |
| Source-drain diode  |                              |  |  |     |      |      |      |
| V <sub>SD</sub>     | source-drain voltage         | I <sub>S</sub> = 25 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C; <a href="#">Fig. 16</a>                                    |  | -   | 0.81 | 1.2  | V    |
| t <sub>rr</sub>     | reverse recovery time        | I <sub>S</sub> = 20 A; dI <sub>S</sub> /dt = -100 A/μs; V <sub>GS</sub> = 0 V;<br>V <sub>DS</sub> = 25 V; T <sub>j</sub> = 25 °C |  | -   | 23.1 | -    | ns   |
| Q <sub>r</sub>      | recovered charge             |  |  | -   | 18.1 | -    | nC   |

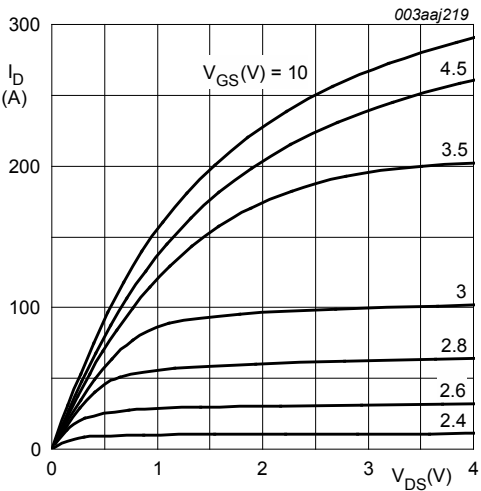


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

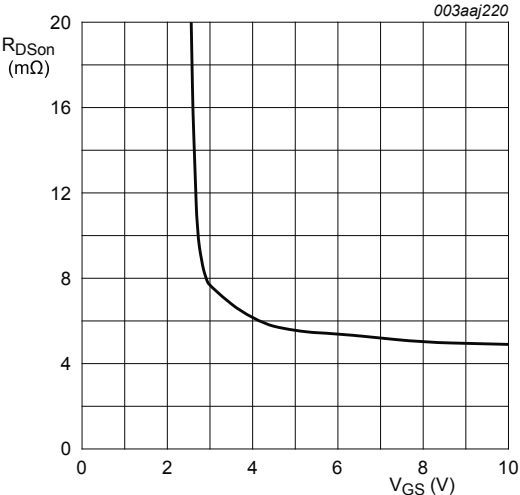


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25\text{ }^{\circ}\text{C}; I_D = 25\text{ A}$

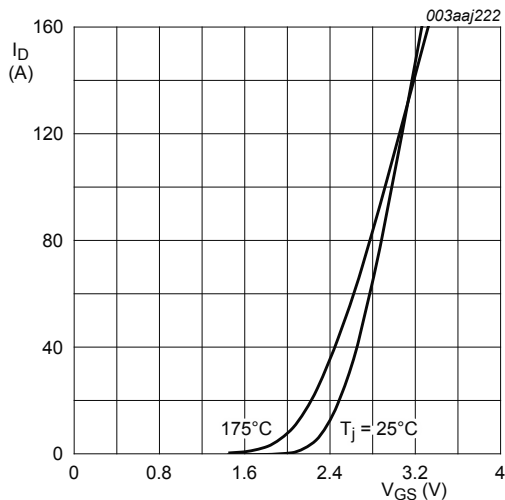


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$V_{DS} = 10\text{V}$

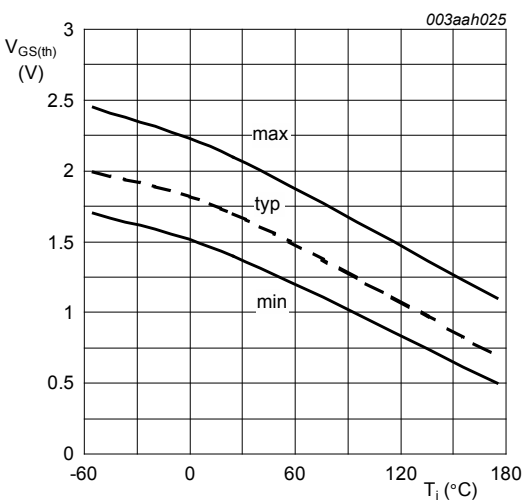


Fig. 9. Gate-source threshold voltage as a function of junction temperature

$I_D = 1\text{ mA}; V_{DS} = V_{GS}$

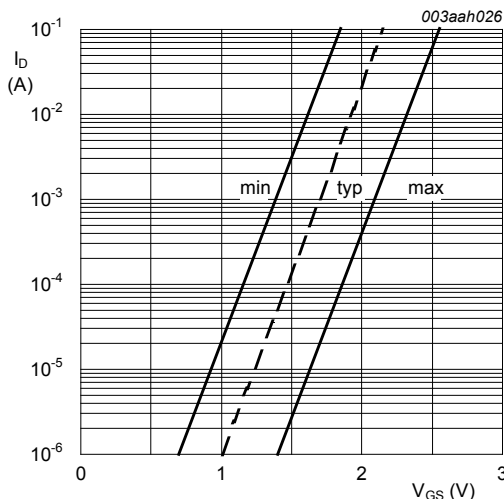
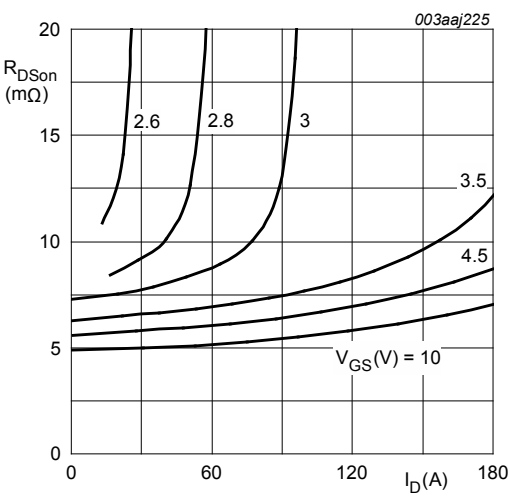


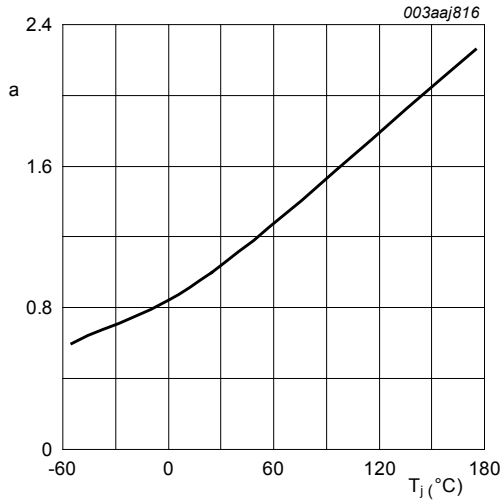
Fig. 10. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25^\circ\text{C}; V_{DS} = 5\text{V}$



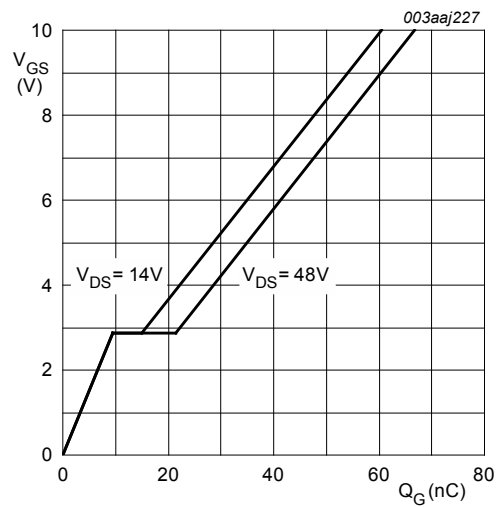
$T_j = 25^\circ\text{C}; t_p = 300\text{ }\mu\text{s}$

Fig. 11. Drain-source on-state resistance as a function of drain current; typical values



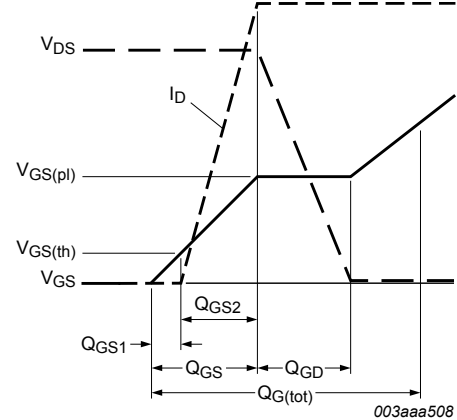
**Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature**

$$a = \frac{R_{DSon}}{R_{DSon}(25^{\circ}\text{C})}$$

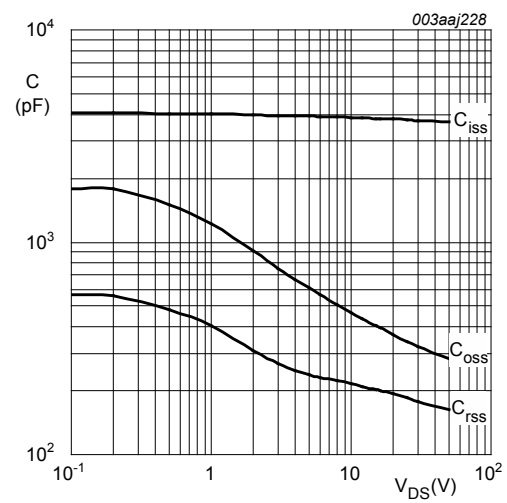


**Fig. 14. Gate-source voltage as a function of gate charge; typical values**

$$T_j = 25^{\circ}\text{C}; I_D = 25\text{A}$$



**Fig. 13. Gate charge waveform definitions**



**Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values**

$$V_{GS} = 0\text{V}; f = 1\text{MHz}$$



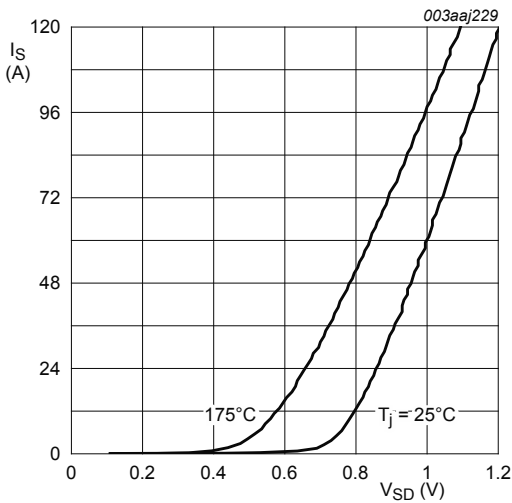


Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values  
 $V_{GS} = 0V$

11. Package outline



Fig. 17. Package outline LPAK56; Power-SO8 (SOT669)

## 12. Legal information

### 12.1 Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
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| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

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Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

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